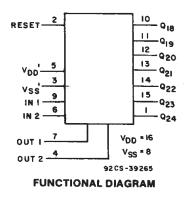


Data sheet acquired from Harris Semiconductor SCHS078C -- Revised October 2003

# CD4521B Types



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# CMOS 24-Stage Frequency Divider

High-Voltage Types (20-Volt Rating)

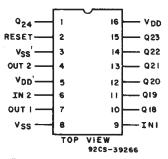
#### Features:

- Reset disables the RC oscillator for lowpower standby condition
- Vod' and Vss' pins are brought out from the crystal oscillator to allow use of
- Maximum input current of 1 µA at 18 V over full package-temperature range: 100 nA at 18 V and 25° C
- Common reset

CD4521B consists of an oscillator section and 24 ripple-carry binary counter stages. The oscillator configuration (using IN1) allows design of either RC or crystal oscillator circuits. IN1 should be tied either HIGH or LOW when not in use. A HIGH on the RESET causes the counter to go to the all-0's state and disables the oscillator. The count is advanced on the negative transition of IN1 (and IN2). A time-saving test mode is described in the Functional Test Sequence Table and in Fig. 6.

The CD4521B types are supplied in 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

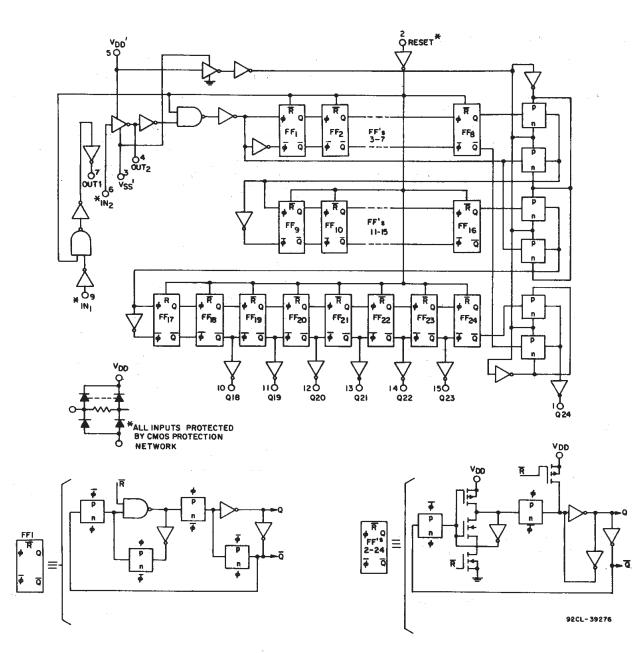
- 100% tested for 20-V quiescent current
- 5, 10 and 15 V parametric ratings
- Standardized symmetrical output characteristics
- external resistors for low-power operation 
  Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series **CMOS Devices**"



**TERMINAL ASSIGNMENT** 

OUTPUT	COUNT CAPACITY
Q18	218 = 262,144
Q19	219 = 524,288
Q20	220 = 1,048,576
Q21	2 <sup>21</sup> = 2,097,152
Q22	222 = 4,194,304
Q23	223 = 8,388,608
Q24	224 = 16,777,216

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE RANGE, (V <sub>DD</sub> )
Voltages referenced to V <sub>SS</sub> Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT
POWER DISSIPATION PER PACKAGE (PD):
For T <sub>A</sub> = -55°C to +100°C
For T <sub>A</sub> = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T <sub>A</sub> = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 $\pm$ 1/32 inch (1.59 $\pm$ 0.79mm) from case for 10s max





#### STATIC ELECTRICAL CHARACTERISTICS

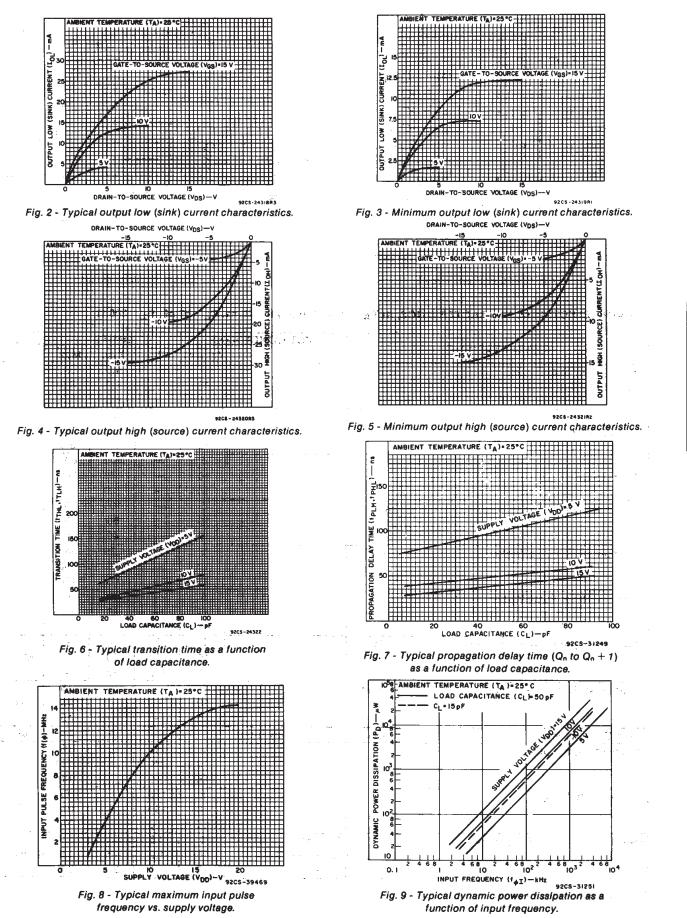
CHARACTERISTIC	со	NDITIO	NS	LIMITS AT INDICATED TEMPERATURES (°C)							
	Vo	VIN	VDD	-55	-40	+85	+125		+25		]
· · · · · · · · · · · · · · · · · · ·	(V)	(V)	(V)					Min.	Тур.	Max.	
	—	0, 5	5	5.	5.	150	150	_	0.04	5	
Quiescent Device		0, 10	10	10	10	300	300		0.04	10	μΑ
Current, IDD Max.	·	0, 15	15	20	20	600	600		0.04	20	
		0, 20	20	100	100	3000	3000		0.08	100	
Output Low (Sink) Current, IoL Min.	0.4	0, 5	5	0.64	0.61	0.42	0.36	0.51	1`	_	1
	0.5	0, 10	10	1.6	1.5	1.1	0.9	1.3	2.6	···	
	1.5	0, 15	15	4.2	4	2.8	2.4	3.4	<b>6.8</b>		mA
	4.6	0, 5	5	-0.64	-0.61	-0.42	-0.36	-0.51	<b>-1</b>		
Output High (Source) Current, Іон Min.	2.5	0, 5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2		]
	9.5	0, 10	10	-1.6	-1.5	1.1	-0.9	-1.3	-2.6		-
	13.5	0, 15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
0		0, 5	5		0.	05		—	0	0.05	
Output Voltage:		0, 10	10		0.	05			0	0.05	
Low-Level, Vol Max.		0, 15	15		0.	05		·	0	0.05	
· · · · · · · · · · · · · · · · · · ·		0,5	5		4.	95		4.95	5		7
Output Voltage:		0, 10	10		9.	95		9.95	10	_	1
High-Level, V <sub>oн</sub> Min.	_	0, 15	15		14	.95	-	14.95	15	—	
	0.5,4.5		5		1	.5		—	·	1.5	7 °
Input Low Voltage,	1, 9	—	10			3				3	1
V <sub>IL</sub> Max.	1.5,13.5	_	15			4		<u> </u>		4	1
	0.5,4.5		5		3	.5		3.5	_	·	1
Input High Voltage,	1.9	_	10	1		7		7	_	_	
V <sub>IH</sub> Min.	1.5,13.5		15		1	1		11			
Input Current, I <sub>IN</sub> Max.		0, 18	18	±0.1	±0.1	±1	±1	<u>†                                     </u>	±10 <sup>-5</sup>	±0.1	μA

RECOMMENDED OPERATING CONDITIONS

5 (j) -

For maximum reliability, nominal operating conditions should be selected so that operating is always within the following ranges:

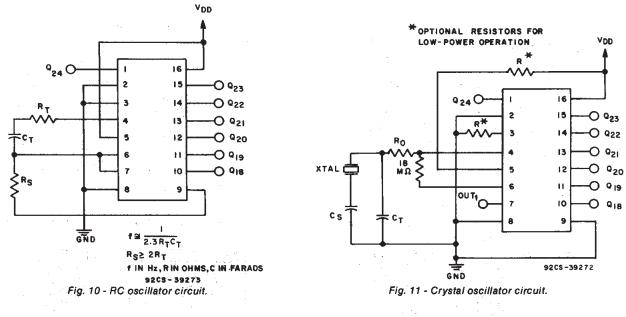
		VDD	LIN	IITS	UNITS
CHARACTERISTIC	(V)	Min.	Max.	UNITS	
Supply-Voltage Range (For TA = Full Package-Temperatu	_	3	18	V	
		5	340	- T	
Input Pulse Width	tw <b>¢</b>	10	150		
	and the second	15	120	_	
		5	180	-	ns
Reset Pulse Width	two	10	80	] _	
		15	50	-	
		5		2	MHz
Input Pulse Frequency	fφ	10	_	5	
		15		6.5	
Litter - Adda		5	- 1	15	μs
Input Pulse Rise or Fall Time	tr∅,tr∅	10	_	15	
		15	-	15	
		5	1K	10M	
R <sub>T</sub> Operating Range		10	1K	10M	Ω
		15	1K	10M	
	t.	5	15p	10M	
C <sub>T</sub> Operating Range		10	15p	10M	F
		15	15p	10M	



COMMERCIAL CMOS HIGH VOLTAGE IC8

3

### CD4521B Types

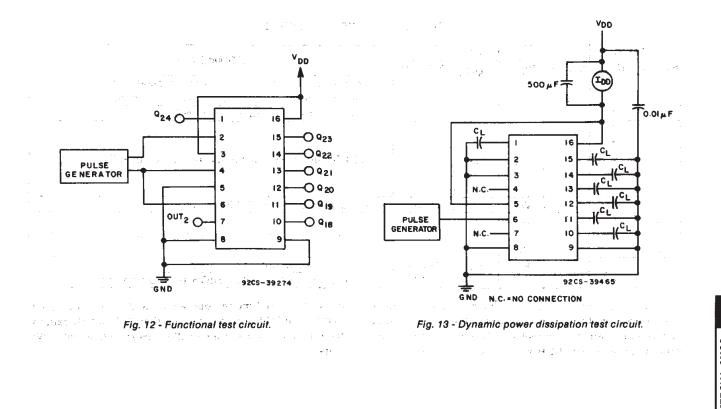


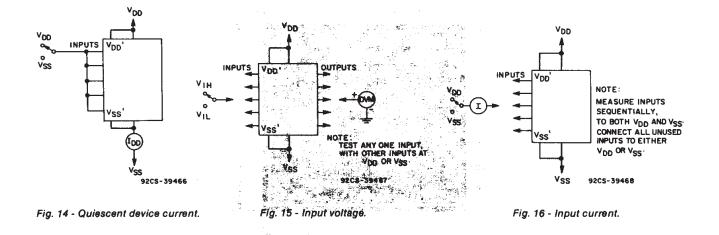
#### DYNAMIC ELECTRICAL CHARACTERISTICS, At T<sub>A</sub> = 25° C; Input t<sub>r</sub>,t<sub>f</sub> = 20 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 200 $\Omega$

011404075010750	÷	TEST CONDITIO	NS	LIMITS				
CHARACTERISTIC			VDD(V)	Min.	Тур.	Max.	UNITS	
Propagation Delay Time:	tPLH, TPHL		5	<u> </u>	4.5	9		
Input to Q18			10	. — .	1.7	3.5		
			15	·	1.3	2.7		
			- 5		6	12	- μs	
Input to Q24			10		2.2	4.5		
	2		15	<del>,</del>	1.7	3.5		
			5	-	400	800		
Reset to Qn			10	·	170	340		
		· · · · · ·	15	· · ·	120	240		
Transition Time*	t <sub>THL</sub> , t <sub>TLH</sub>	1	5	<u> </u>	100	200	]	
•.		· ·	10		50	100		
		1 (A)	15	. <u> </u>	40	80		
Minimum Input Pulse Width	t <sub>w</sub> ¢		5	·	170	. 340	- ns	
			10		75	150		
		1	15	· · -	60	120		
Minimum Reset Pulse Width	t <sub>w(R)</sub>	A a Ma	5		90	180	7	
			10		40	80		
			15		25	50		
Maximum Input Pulse Frequency	fφ		5	2	4	— <sup> </sup>		
1. All 1.			10	5	10	_	MHz	
and the second			15	6.5	13			
Input Pulse Rise or Fall Time	$t_r \phi, t_f \phi$		5		-	15		
			10			15	μs	
			15	. —	1 ·	15		
Input Capacitance	CIN	Any Input		·	5	7.5	pF	
R <sub>T</sub> Operating Range		a ta a a	5	1K -	-	10M		
			10	1K	-	10M	Ω	
			15	1K	— <sup>-</sup>	-10M		
C <sub>T</sub> Operating Range			5	15p	—	10µ		
		1	10	15p	-	10µ	F	
		· · · · · · · · · · · · · · · · · · ·	15	15p	<u> </u>	10µ		
Maximum Oscillator Frequency		R <sub>τ</sub> =1 KΩ	5	0.5	0.7	0.9		
· · ·		Ст=15 рГ	10	1.2	1.5	1.8	MHz	
		Rs=30 KΩ	15	1.7	2.1	2.5		

\*Not applicable for pin 4 (OUT2).

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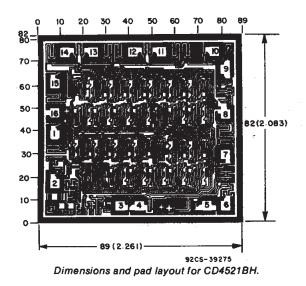
\*

COMMERCIAL CMOS

#### CD4521B Types

INPL	JTS		OU.	TPUTS		COMMENTS
RESET	IN 2	OUT 2	V <sub>SS</sub> '	VDD'	Q18-Q24	COMMENTS
	2					Counter is in three 8-stage sections in parallel mode.
1	0	0	Voo	Vss	LOW	Counter is reset. IN 2 and OUT 2 are tied together.
· 0	1	1	Voo	Vss		First LOW-to-HIGH transition at IN 2.
	0	0			1	
	1	1		ŀ		
0	_	_	VDD	Vss		255 LOW-to-HIGH transitions are clocked in at IN 2.
	-	_		]		·
	—	_				
0	1	1	VDD	Vss	HIGH	The 255th LOW-to-HIGH transition.
0	0	0	Vod	Vss	HIGH	
0	0	0	Vss	Vss	HIGH	Counter is converted back to 24-stage serial-mode operation.
0	1	0	Vss	VDD	HIGH	
0	1		Vss	VDD	HIGH	OUT 2 reverts to output operation.
0	0	1	Vss	VDD	LOW	Counter ripples from an all-HIGH state to an all-LOW state.

A test function, which divides, has been included to reduce the time required to test all 24 stages of the counter. Three sections are loaded in parallel to 255 counts, forcing all the outputs to be in the HIGH state. The counter is changed back to serial-mode operation and one additional LOW-to-HIGH transition is entered at IN 2, which causes the outputs to ripple from an all-HIGH state to an all-LOW state.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils  $(10^{-3} \text{ inch})$ .



#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
CD4521BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4521BE	Samples
CD4521BEE4	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4521BE	Samples
CD4521BM	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	CD4521BM	
CD4521BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4521BM	Samples
CD4521BMT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	CD4521BM	
CD4521BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4521B	Samples
CD4521BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM521B	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All	dimensions are nominal												
Γ	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	CD4521BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
	CD4521BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1



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### PACKAGE MATERIALS INFORMATION

25-Sep-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD4521BM96	SOIC	D	16	2500	353.0	353.0	32.0	
CD4521BNSR	SO	NS	16	2000	356.0	356.0	35.0	

### TEXAS INSTRUMENTS

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25-Sep-2024

#### TUBE



### - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD4521BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4521BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4521BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4521BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4521BPW	PW	TSSOP	16	90	530	10.2	3600	3.5

# **NS0016A**



### **PACKAGE OUTLINE**

SOP - 2.00 mm max height

SOP



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- Per ASME Y14.5M.
   This drawing is subject to change without notice.
   This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



# NS0016A

# **EXAMPLE BOARD LAYOUT**

### SOP - 2.00 mm max height

SOP



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# NS0016A

# **EXAMPLE STENCIL DESIGN**

### SOP - 2.00 mm max height

SOP



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



# **PW0016A**



### **PACKAGE OUTLINE**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



### PW0016A

# **EXAMPLE BOARD LAYOUT**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### PW0016A

# **EXAMPLE STENCIL DESIGN**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



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